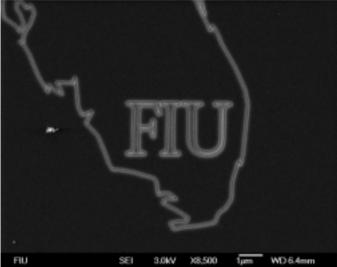


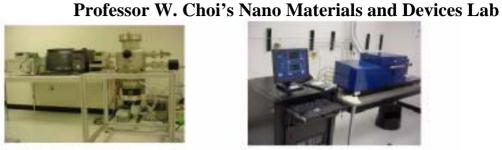
Nano Fabrication Research at FIU



FIU logo with 25nm line width by e-beam lithography

- Fastest growing University in the US- Ranked in top 25 largest Universities (34,000 students)
- Research I status- highest ranking in shortest time
- Minority Institution- designated a Hispanic Serving Inst itution (HIS) - only one of two with Research I status
- External research in excess 0f \$60MM, with 20% growt h every year for the past 6 years
- College of Engineering (COE) offers Ph.D. in ME, EE, CE and MS in MSE, BioMed, Environ. Eng., IE, Eng. M anagement. Ph.D. in Materials Science in process

Nanotechnology processing **Facilities in FIU (AMRIE)**



Field Emission System



Photo Lithography Room (100 class)



CNT growth CVD System



Nano Processing Clean Room (10,000 class)



 Characterization and Processing Laboratories; thermal processing, thermal characterizatio mechanical characterization and processing Analytical Instrumentation Laboratory; SPM, SEM, TEM

Focused Ion Beam system



Nano E-beam Source

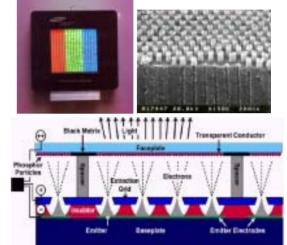
Goal

- •Develop nano scale electron beam source
- •High current density generator, High power generator, and field emission display(compact size & flat panel)

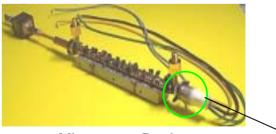
Advantages

- -. High aspect ratio
- -. High electrical conductivity
- -. High thermal conductivity
- -. Rigidity

Field emission display



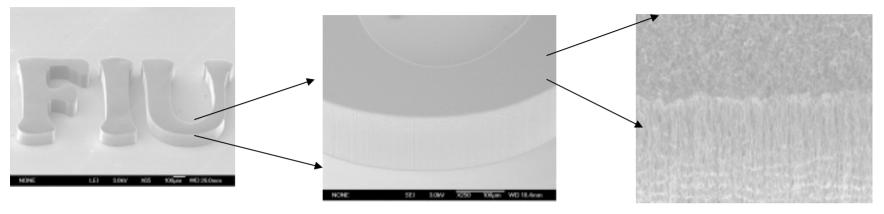
W.B. Choi et al., Appl. Phys. Lett. 75 3129 Nov. (1999)W. Choi et al., Adv. Fun. Mat. 80 13 Jan. (2003)



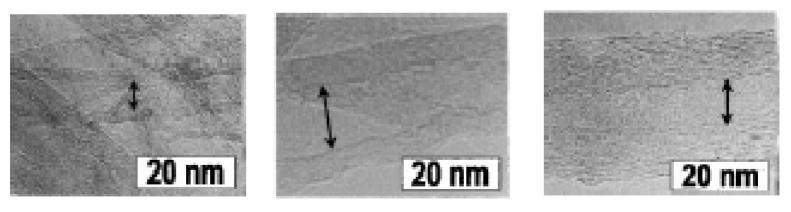
Microwave Device (Pierce-type gun)



Selective Growth and Vertically aligned Carbon nanotubes



- Number of graphitic wall is controlled by size of catalyst particle. *-* Field emission properties is being investigated with structural change.

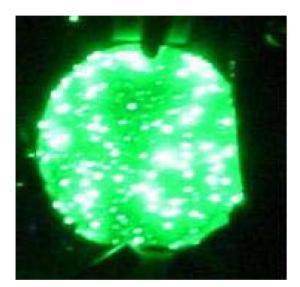


4 walls

10 walls

25 walls

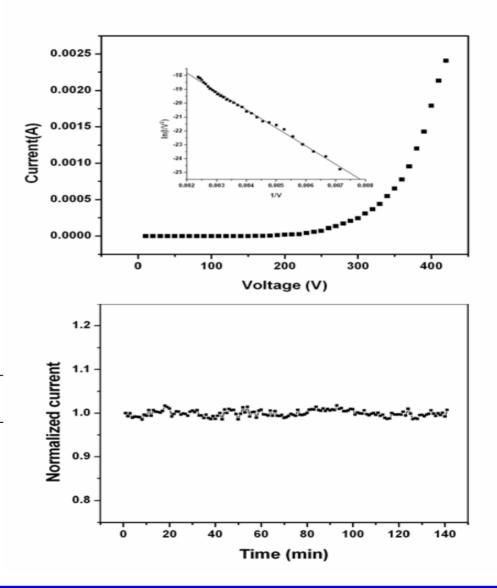
(Y. Choi et al. Appl. Phys. Lett.) Center for Nano Materials & Devices **Field Emission Characterization from Multiwall Carbon nanotube**



FLORIDA

Miami's public research university

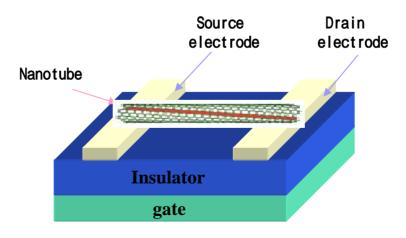
Emission pattern of thin MWCNT grown by CVD





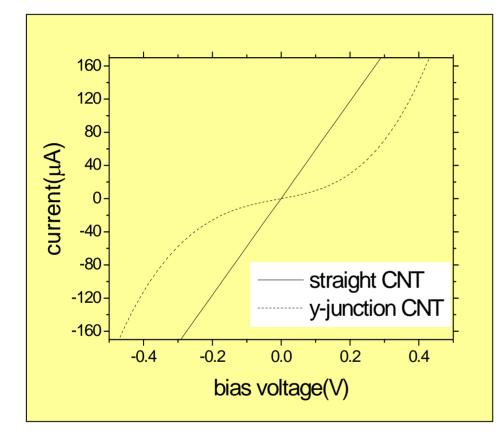
CNT for Electronics

- Low dimension --> Tera-level high density device
- Low power consumption
- High current carrying capacity (1 X 10¹⁰ A/cm²)
- Heat dissipation (6000 W/m.K)
- High mobility (Quasi Ballistic) for charge transport

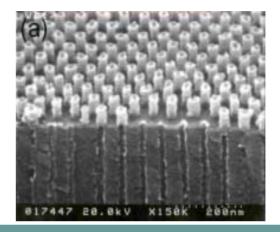




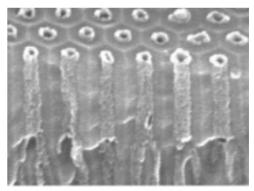
Y-shape CNT arrays



I-V data of straight- & Y-shape CNT



SEM image of straight CNT



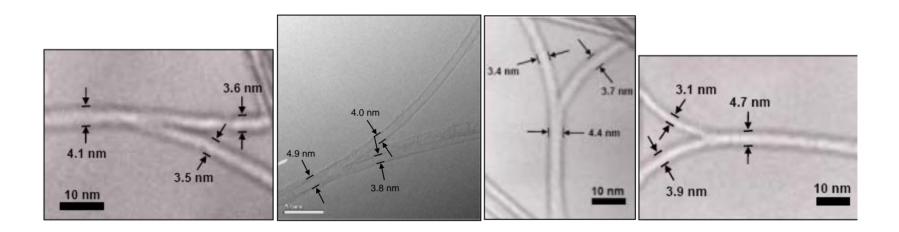
150nm

SEM image of Y-shape CNT

W. Choi et al, Nanotechnology 2004



<< This is the first report on the TEM images of Y-junction SWNTs >>

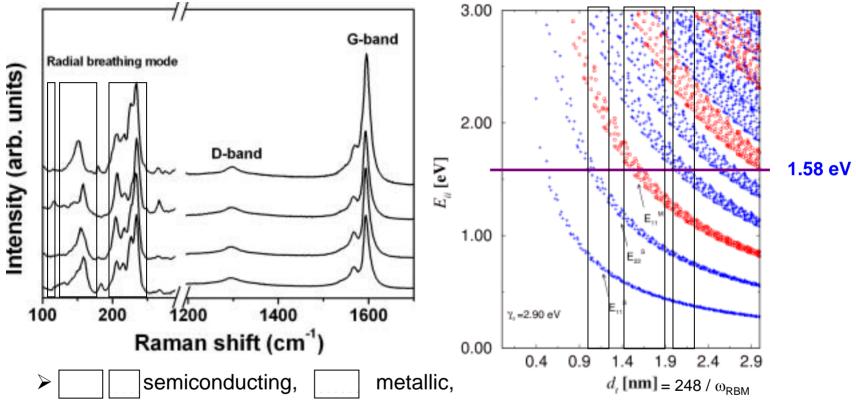


- Branch SWNTs seem to be nucleated and grown from the wall of stem SWNTs.
- Three individual SWNTs with different diameters.
- > Diameters of stems (4 5 nm) is larger than those of branches (3 4 nm).
- Interestingly, the diameter of stem decreases after branching occurs.



Raman spectra of Y-junction SWNTs

(Grown at 900 °C, 785 nm-laser)



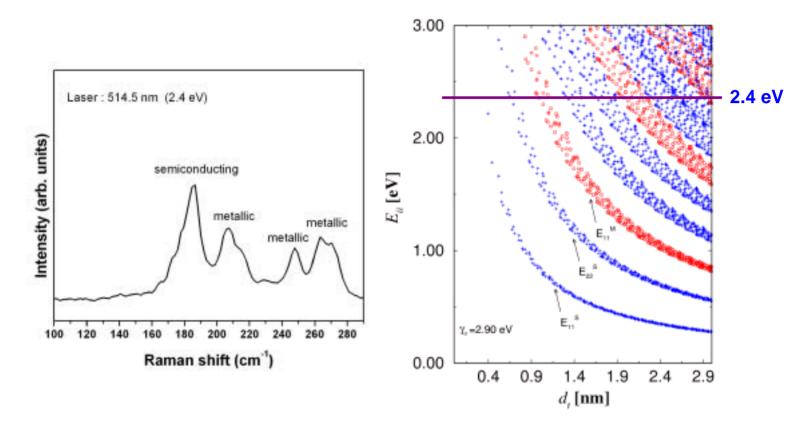
indicating possible formation of Y-SWNTs with different electrical properties

- \succ Dia. : 1 2.25 nm, larger diameters could not be detected due to measuring limitation.
- ➤ two components of G-band and RBM peaks reveal SWNTs.
- > very weak D-band : proof of exclusive existence of SWNTs.



Raman spectra of Y-junction SWNTs

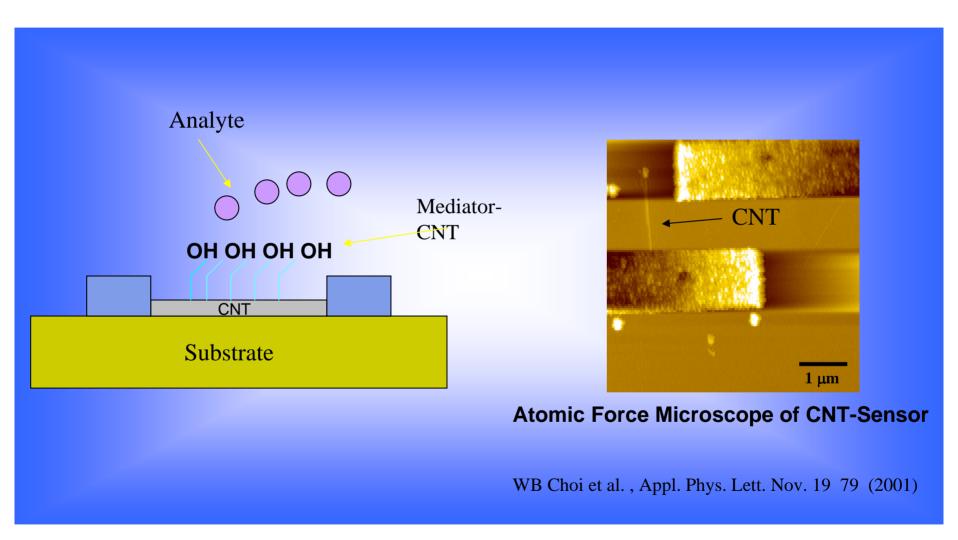
(Grown at 900 °C, 514.5 nm-laser)



> This also show the existence of both metallic and semiconducting SWNTs.



CNTs for Sensor

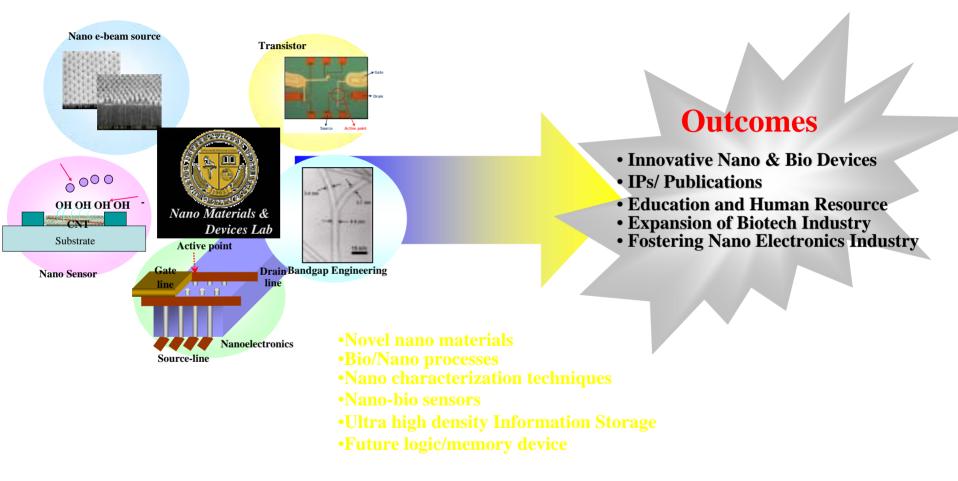






- Raman analysis revealed that the majority of the nanotubes in the Y-junction SWNT are semiconducting as compared to SWNT which are both metallic and semiconducting.
- ✤Upon functionalisation with PVOH, nanotubes show a drastic decrease in the contact angles which signifies the increase in the wettability and increase in hydrophillic nature.
- Impedance measurements showed that functionalised Y-SWNT have high sensitivity for relative humidity changes.







Director: Prof. Wonbong Choi Research Scientist: Dr. Somaneth Roy Dr. Do-hyun Kim Dr. Young-chul Choi (Samsung)

Ph.D. Students: Jun Huang Harindra Vedala_Narasimha Raghunandan Seelaboyina Yong Gao Rao Bangalore Michael Mellow